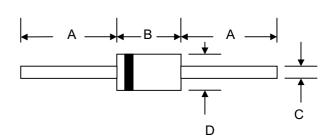
## **SEMICONDUCTOR**

### 3.0A SCHOTTKY BARRIER RECTIFIER

## Data Sheet 2827, Rev.-

#### **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications



#### **Mechanical Data**

Case: Molded Plastic

Terminals: Plated Leads Solderable per

MIL-STD-202, Method 208

Polarity: Cathode BandWeight: 1.2 grams (approx.)

Weight: 1.2 grains (approx
 Mounting Position: Any

Marking: Type Number

DO-201AD									
Dim	Min	Max	Min	Max					
Α	25.40	_	1.000	_					
В	8.50	9.50	0.334	0.374					
С	1.20	1.30	0.047	0.051					
D	5.00	5.60	0.197	0.220					
	In mm		In inch						

## Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SB320	SB330	SB340	SB350	SB360	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		VRRM VRWM VR	20	30	40	50	60	V
RMS Reverse Voltage		VR(RMS)	14	21	28	35	42	٧
Average Rectified Output Current (Note 1) @T <sub>L</sub> = 95°C		lo	3.0					Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		lғsм	80					Α
Forward Voltage	@I <sub>F</sub> = 3.0A	VFM	0.50		0.74		٧	
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$		lгм	0.5 20					mA
Typical Junction Capacitance (Note 2)		Cj	250					pF
Typical Thermal Resistance Junction to Ambient		$R_{ heta}$ JA	20					K/W
Operating and Storage Temperature Range		Тj, Tsтg	-65 to +150					°C

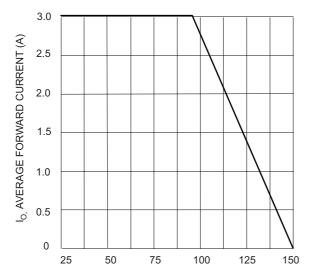
Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.

2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

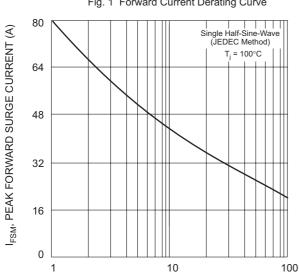
<sup>• 221</sup> West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FA (631) 242-9798 •

<sup>•</sup> World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •

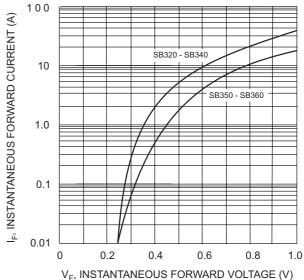




T<sub>L</sub>, LEAD TEMPERATURE (°C) Fig. 1 Forward Current Derating Curve



NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Fwd Surge Current



V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (\)
Fig. 2 Typical Forward Characteristics

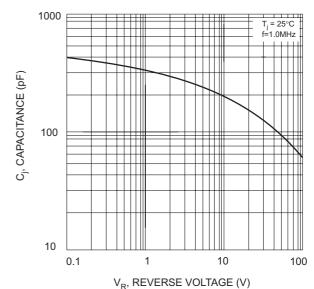
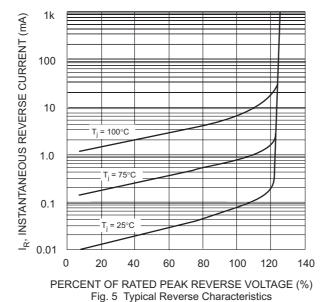


Fig. 4 Typical Junction Capacitance



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